# Old Company Name in Catalogs and Other Documents

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## COMPOUND FIELD EFFECT POWER TRANSISTOR



**μPA1552B** 

## N-CHANNEL POWER MOS FET ARRAY SWITCHING USE

#### **DESCRIPTION**

The  $\mu$ PA1552B is N-channel Power MOS FET Array that built in 4 circuits designed, for solenoid, motor and lamp driver.

#### **FEATURES**

- · 4 V driving is possible
- Large Current and Low On-state Resistance
   ID(DC) = ±5.0 A

 $R_{DS(on)1} \le 0.18 \ \Omega \ MAX. \ (V_{GS} = 10 \ V, \ I_{D} = 3 \ A)$  $R_{DS(on)2} \le 0.24 \ \Omega \ MAX. \ (V_{GS} = 4 \ V, \ I_{D} = 3 \ A)$ 

 $NDS(00)/2 \le 0.24 \le 2 \text{ IVIAX.} (VGS = 4 \text{ V}, ID = 3 \text{ A})$ 

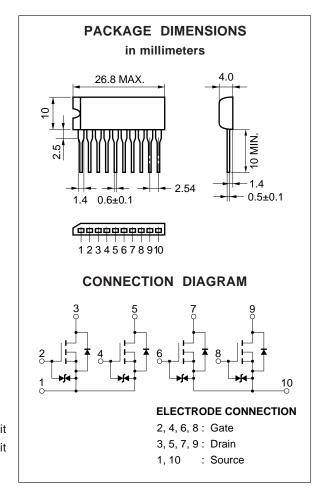
• Low Input Capacitance Ciss = 200 pF TYP.

#### ORDERING INFORMATION

Type Number	Package	
μPA1552BH	10 Pin SIP	

### ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

Drain to Source Voltage	VDSS Note 1	60	V
Gate to Source Voltage	VGSS Note 2	±20	V
Drain Current (DC)	I <sub>D(DC)</sub>	±5.0	A/unit
Drain Current (pulse)	I <sub>D(pulse)</sub> Note 3	±20	A/unit
Total Power Dissipation	PT1 Note 4	28	W
Total Power Dissipation	PT2 Note 5	3.5	W
Channel Temperature	Тсн	150	$\mathbb{C}$
Storage Temperature	Tstg	-55 to +150	$\mathbb{C}$
Single Avalanche Current	IAS Note 6	5.0	Α
Single Avalanche Energy	EAS Note 6	2.5	mJ



- Notes 1. Vgs = 0
  - **3.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1 %
  - 5. 4 Circuits, T<sub>A</sub> = 25 °C
- **2.**  $V_{DS} = 0$
- 4. 4 Circuits, Tc = 25 °C
- **6.** Starting TcH = 25 °C, V DD = 30 V, VGS = 20 V  $\rightarrow$  0, RG = 25  $\Omega$ , L = 100  $\mu$ H

The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device is actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.



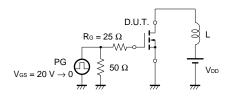


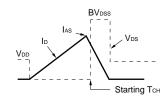
## ELECTRICAL CHARACTERISTICS (TA = 25 °C)

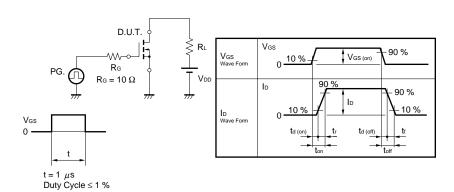
CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain Leakage Current	IDSS	V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0			10	μΑ
Gate Leakage Current	Igss	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0			±10	μΑ
Gate Cutoff Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1.0 mA	1.0		2.0	V
Forward Transfer Admittance	Yfs	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 3.0 A	2.4			S
Drain to Source On-State	RDS(on)1	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 3.0 A		0.09	0.18	Ω
Resistance	RDS(on)2	V <sub>GS</sub> = 4.0 V, I <sub>D</sub> = 3.0 A		0.12	0.24	Ω
Input Capacitance	Ciss	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0, f = 1.0 MHz		200		pF
Output Capacitance	Coss			150		pF
Reverse Transfer Capacitance	Crss			55		pF
Turn-on Delay Time	td(on)	ID = 3.0 A, VGS = 10 V, VDD $\rightleftharpoons$ 30 V, RL = 10 $\Omega$		20		ns
Rise Time	tr			100		ns
Turn-off Delay Time	td(off)			670		ns
Fall Time	<b>t</b> f			310		ns
Total Gate Charge	Q <sub>G</sub>	Vgs = 10 V, ID = 5.0 A, VDD = 48 V		13		nC
Gate to Source Charge	Qgs			2		nC
Gate to Drain Charge	Q <sub>GD</sub>			4.7		nC
Body Diode Forward Voltage	V <sub>F</sub> (S-D)	IF = 5.0 A, VGS = 0		1.0		V
Reverse Recovery Time	trr	$I_F = 5.0 \text{ A}, \text{ Vgs} = 0, \text{ di/dt} = 50 \text{ A/}\mu\text{s}$		280		ns
Reverse Recovery Charge	Qrr			820		nC

## Test Circuit 1 Avalanche Capability

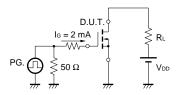
## Test Circuit 2 Switching Time







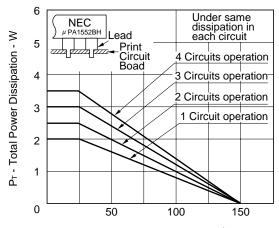
### Test Circuit 3 Gate Charge





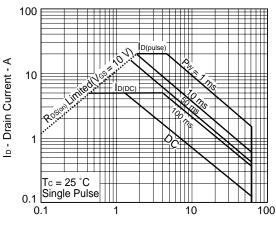
## CHARACTERISTICS (TA = 25 °C)

# TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE

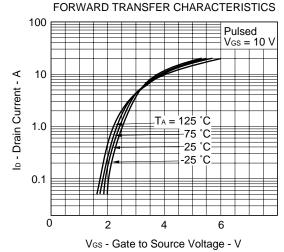


T<sub>A</sub> - Ambient Temperature - °C

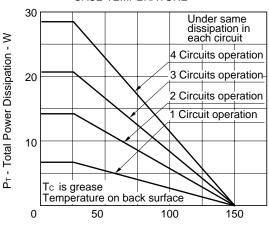
#### FORWARD BIAS SAFE OPERATING AREA



V<sub>DS</sub> - Drain to Source Voltage - V

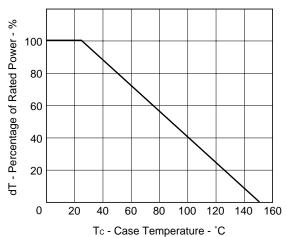


TOTAL POWER DISSIPATION vs. CASE TEMPERATURE

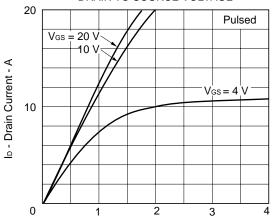


Tc - Case Temperature - °C

# DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA

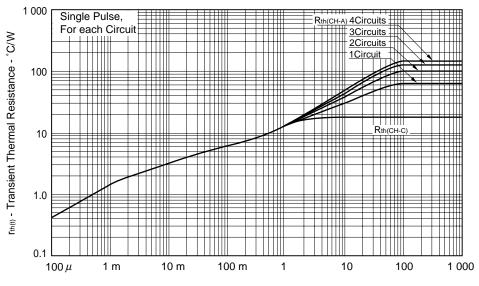


DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE

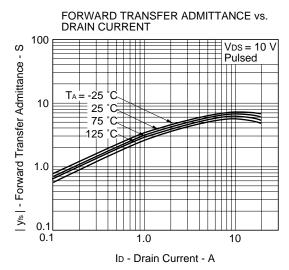


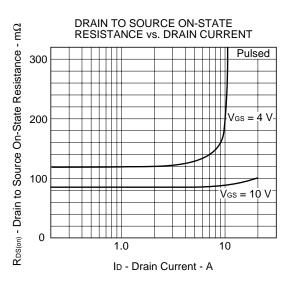
 $V_{\text{\scriptsize DS}}$  - Drain to Source Voltage - V

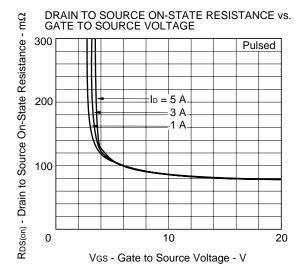
### TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

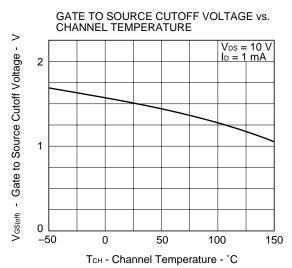


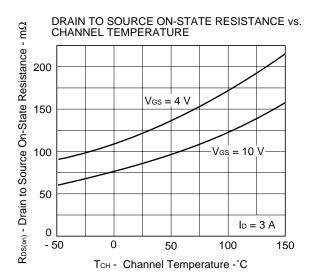
PW - Pulse Width - sec

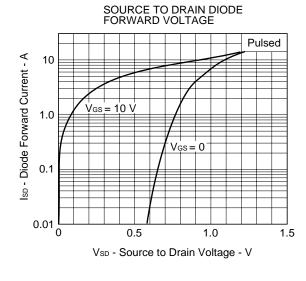


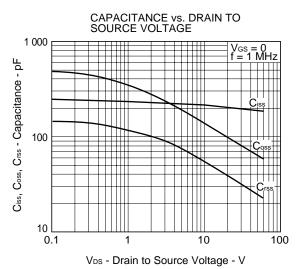


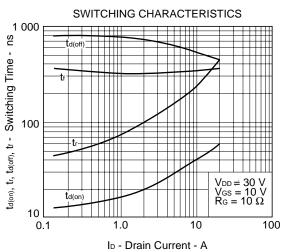


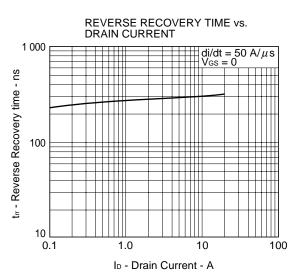


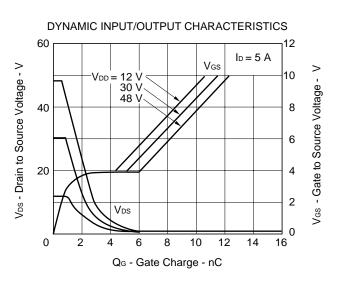






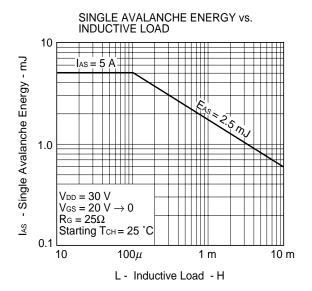


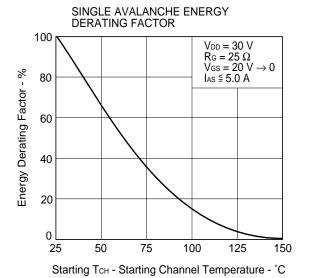












**REFERENCE** 

Document Name	Document No.
NEC semiconductor device reliability/quality control system	TEI-1202
Quality grade on NEC semiconductor devices	IEI-1209
Semiconductor device mounting technology manual	IEI-1207
Semiconductor device package manual	IEI-1213
Guide to quality assurance for semiconductor devices	MEI-1202
Semiconductor selection guide	MF-1134
Power MOS FET features and application switching power supply	TEA-1034
Application circuits using Power MOS FET	TEA-1035
Safe operating area of Power MOS FET	TEA-1037

[MEMO]



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